July 2015

**FDMC7660DC** N-Channel Dual Cool<sup>™</sup> 33 PowerTrench<sup>®</sup> MOSFET

30 V, 40 A, 2.2 m $\Omega$ 

FAIRCHILD

## Features

- Dual Cool<sup>TM</sup> Top Side Cooling PQFN package
- Max  $r_{DS(on)}$  = 2.2 m $\Omega$  at V<sub>GS</sub> = 10 V, I<sub>D</sub> = 22 A
- Max  $r_{DS(on)}$  = 3.3 m $\Omega$  at V<sub>GS</sub> = 4.5 V, I<sub>D</sub> = 18 A
- High performance technology for extremely low r<sub>DS(on)</sub>
- SyncFET Schottky Body Diode
- RoHS Compliant

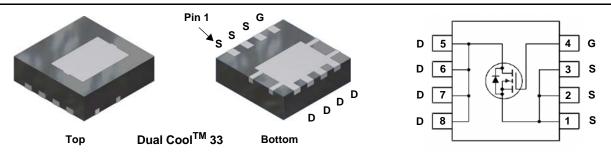


## **General Description**

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process. Advancements in both silicon and Dual Cool<sup>TM</sup> package technologies have been combined to offer the lowest  $r_{DS(on)}$  while maintaining excellent switching performance by extremely low Junction-to-Ambient thermal resistance.

## Applications

- Synchronous Rectifier for DC/DC Converters
- Telecom Secondary Side Rectification
- High End Server/Workstation



MOSFET Maximum Ratings TA= 25°C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V <sub>DS</sub>	Drain to Source Voltage			30	V	
V <sub>GS</sub>	Gate to Source Voltage		(Note 4)	±20	V	
	Drain Current -Continuous (Package limited)	T <sub>C</sub> = 25 °C		40		
	-Continuous (Silicon limited)	T <sub>C</sub> = 25 °C		150	A	
D	-Continuous	T <sub>A</sub> = 25 °C	(Note 1a)	30	A	
	-Pulsed			200		
E <sub>AS</sub>	Single Pulse Avalanche Energy (1		(Note 3)	220	mJ	
dv/dt	Peak Diode Recovery dv/dt		(Note 5)	1.0	V/ns	
P <sub>D</sub>	Power Dissipation	T <sub>C</sub> = 25 °C		78	w	
	Power Dissipation	T <sub>A</sub> = 25 °C	(Note 1a)	3.0	VV	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range			-55 to + 150	°C	

## **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Top Source)	4.3	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.6	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	42	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	105	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1i)	17	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1j)	26	
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1k)	12	

## Package Marking and Ordering Information

ſ	Device Marking	Device	Package	Reel Size	Tape Width	Quantity
	7660	FDMC7660DC	Dual Cool <sup>TM</sup> 33	13"	12 mm	3000 units

DMC76
60DC N
-Chann
el Dual (
Cool <sup>TM</sup>
33 Pow
DMC7660DC N-Channel Dual Cool <sup>TM</sup> 33 PowerTrench <sup>®</sup> I
h <sup>®</sup> MOS
MOSFET

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		$v_{GS} = 10^{-1} v_{1} I_{D} = 22^{-1} V_{1}$	
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	66 · D	
		$V_{GS} = 10 \text{ V}, I_D = 22 \text{ A}, T_J = 125^{\circ}\text{C}$	
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 5 V, I <sub>D</sub> = 22 A	
Dynami	c Characteristics		
C <sub>iss</sub>	Input Capacitance		
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$	
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1MHz	
R <sub>g</sub>	Gate Resistance		
	ng Characteristics		
	Turn-On Delay Time		
t <sub>d(on)</sub> t <sub>r</sub>	Rise Time		
	Turn-Off Delay Time	$V_{DD}$ = 15 V, I <sub>D</sub> = 22 A, V <sub>GS</sub> = 10 V, R <sub>GEN</sub> = 6 Ω	
t <sub>d(off)</sub> t <sub>f</sub>	Fall Time		
Q <sub>g</sub>	Total Gate Charge	V <sub>GS</sub> = 0 V to 10 V	
Q <sub>g</sub>	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 15 V,$	
Q <sub>gs</sub>	Gate to Source Charge	$I_{\rm D} = 22 \text{ A}$	
Q <sub>gd</sub>	Gate to Drain "Miller" Charge		
	Source Drain Diade, Ferward Valtage	$V_{GS} = 0 V, I_S = 22 A$ (Note 2)	
V <sub>SD</sub>	Source-Drain Diode Forward Voltage	$V_{} = 0 V_{} = 10 \Lambda$ (Note 2)	
		$V_{GS} = 0 V, I_S = 1.9 A$ (Note 2)	
V <sub>SD</sub>	Reverse Recovery Time	$V_{GS} = 0 V, I_S = 1.9 A$ (Note : 	

Electrical Characteristics T<sub>J</sub> = 25°C unless otherwise noted

**Test Conditions** 

 $I_D = 250 \ \mu$ A, referenced to 25 °C

 $I_D = 250 \ \mu A$ , referenced to 25 °C

 $I_D = 250 \ \mu\text{A}, \ V_{\text{GS}} = 0 \ \text{V}$ 

 $V_{DS} = 24 V, V_{GS} = 0 V$  $V_{GS} = 20 V, V_{DS} = 0 V$ 

 $V_{GS}=V_{DS},\,I_{D}=250~\mu A$ 

 $V_{GS} = 10 V, I_D = 22 A$ 

Min

30

1.2

Тур

15

2

-7

1.6

2.5

2.2

147

3885

1215

100

0.7

17

6.6

36

5

54

24

13

5.5

0.8

0.7

43

24

Max

1

100

2.5

2.2

3.3

3.3

5170

1620

150

1.5

31

13

58

10

76

34

1.2

1.2

69

38

Units

V

mV/°C

μΑ

nA

V

mV/°C

mΩ

S

pF

pF

pF

Ω

ns

ns

ns

ns

nC

nC

nC

nC

V

ns

nC

Parameter

Gate to Source Leakage Current, Forward

Drain to Source Breakdown Voltage

Breakdown Voltage Temperature

Zero Gate Voltage Drain Current

Gate to Source Threshold Voltage

Gate to Source Threshold Voltage

**Temperature Coefficient** 

Symbol

 $BV_{DSS}$  $\frac{\Delta BV_{DSS}}{\Delta T_{J}}$ 

I<sub>DSS</sub>

I<sub>GSS</sub>

V<sub>GS(th)</sub>  $\frac{\Delta V_{GS(th)}}{\Delta T_J}$ 

**Off Characteristics** 

**On Characteristics** 

Coefficient

## **Thermal Characteristics**

$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Top Source)	4.3	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Bottom Drain)	1.6	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	42	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	105	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1c)	29	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1d)	40	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1e)	19	00 AM
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1f)	23	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1g)	30	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1h)	79	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1i)	17	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1j)	26	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1k)	12	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1I)	16	

NOTES:

1. R<sub>0JA</sub> is determined with the device mounted on a FR-4 board using a specified pad of 2 oz copper as shown below. R<sub>0JC</sub> is guaranteed by design while R<sub>0CA</sub> is determined by the user's board design.



a. 42 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper



b. 105 °C/W when mounted on a minimum pad of 2 oz copper

c. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in<sup>2</sup> pad of 2 oz copper

d. Still air, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

e. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in<sup>2</sup> pad of 2 oz copper

f. Still air, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

g. 200FPM Airflow, No Heat Sink,1 in<sup>2</sup> pad of 2 oz copper

h. 200FPM Airflow, No Heat Sink, minimum pad of 2 oz copper

i. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, 1 in<sup>2</sup> pad of 2 oz copper

j. 200FPM Airflow, 20.9x10.4x12.7mm Aluminum Heat Sink, minimum pad of 2 oz copper

k. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, 1 in<sup>2</sup> pad of 2 oz copper

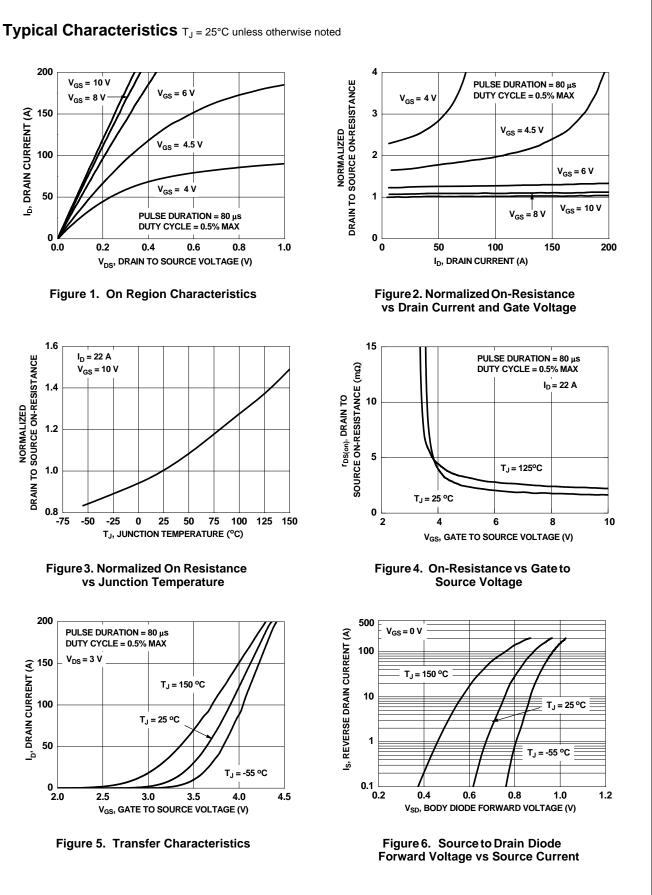
I. 200FPM Airflow, 45.2x41.4x11.7mm Aavid Thermalloy Part # 10-L41B-11 Heat Sink, minimum pad of 2 oz copper

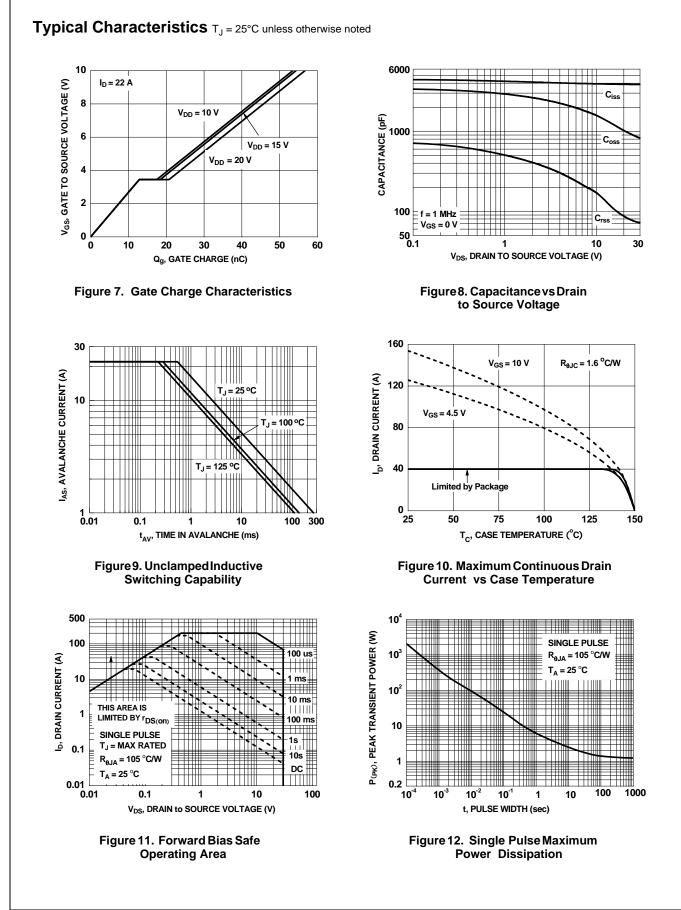
2. Pulse Test: Pulse Width < 300  $\mu$ s, Duty cycle < 2.0%.

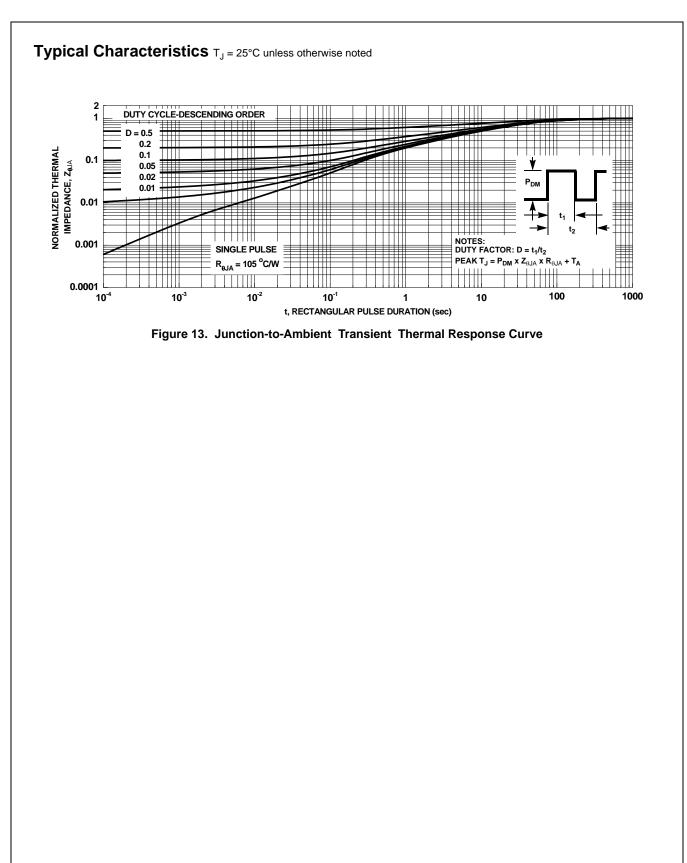
3. E<sub>AS</sub> of 220 mJ is based on starting T<sub>J</sub> = 25  $^{\circ}$ C; N-ch: L = 1 mH, I<sub>AS</sub> = 21 A, V<sub>DD</sub> = 27 V, V<sub>GS</sub> = 10 V. 100% test at L = 0.3 mH, I<sub>AS</sub> = 33.5 A.

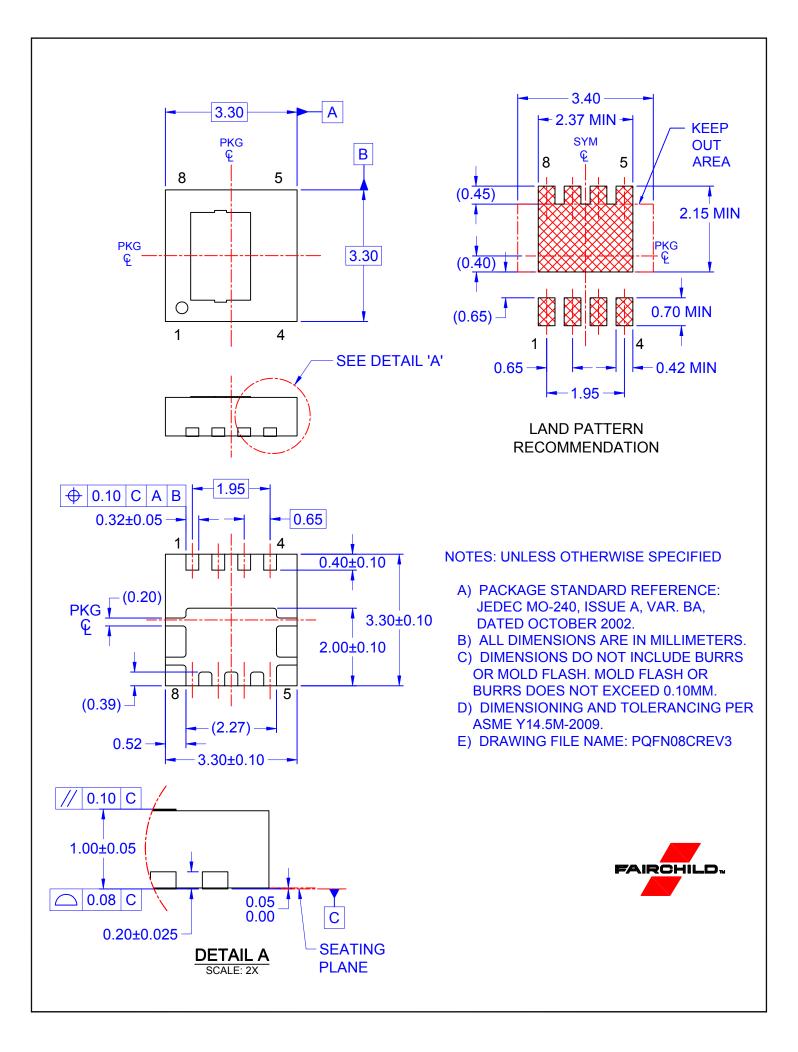
4. As an N-ch device, the negative Vgs rating is for low duty cycle pulse ocurrence only. No continuous rating is implied.

5.  $I_{SD} \leq$  22 A, di/dt  $\leq$  100 A/µs,  $V_{DD} \leq BV_{DSS},~$  Starting  $T_J$  = 25 °C.











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